

# 7MBR100VR060-50

**IGBT Modules**

## IGBT MODULE (V series)

### 600V / 100A / PIM

#### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant product

#### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply



#### ■ Maximum Ratings and Characteristics

##### ● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	$V_{CES}$			600	V
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V
	Collector current	$I_c$	Continuous	$T_c=80^\circ\text{C}$	100	A
		$I_{cp}$	1ms	$T_c=80^\circ\text{C}$	200	
		$-I_c$			100	
$-I_c$ pulse		1ms			200	
Collector power dissipation	$P_c$	1 device		335	W	
Brake	Collector-Emitter voltage	$V_{CES}$			600	V
	Gate-Emitter voltage	$V_{GES}$			$\pm 20$	V
	Collector current	$I_c$	Continuous	$T_c=80^\circ\text{C}$	50	A
		$I_{cp}$	1ms	$T_c=80^\circ\text{C}$	100	
	Collector power dissipation	$P_c$	1 device		215	W
Repetitive peak reverse voltage (Diode)	$V_{RRM}$			600	V	
Converter	Repetitive peak reverse voltage	$V_{RRM}$			800	V
	Average output current	$I_o$	50Hz/60Hz, sine wave		100	A
	Surge current (Non-Repetitive)	$I_{FSM}$	10ms, $T_j=150^\circ\text{C}$		700	A
	$I^2t$ (Non-Repetitive)	$I^2t$	half sine wave		2450	$\text{A}^2\text{s}$
Junction temperature	$T_j$	Inverter, Brake		175	$^\circ\text{C}$	
		Converter		150		
Operating junction temperature (under switching conditions)	$T_{jop}$	Inverter, Brake		150		
		Converter		150		
Case temperature	$T_c$			125		
Storage temperature	$T_{stg}$			-40~+125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	$V_{iso}$	AC : 1min.		2500	VAC
Screw torque	Mounting (*3)	-	M5		3.5	N m

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

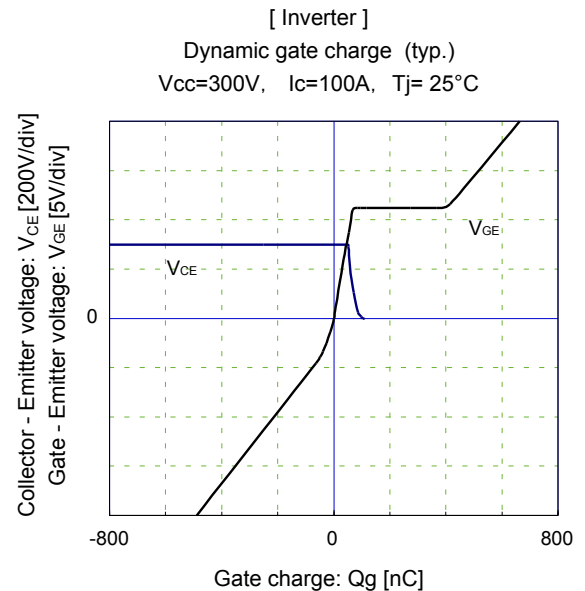
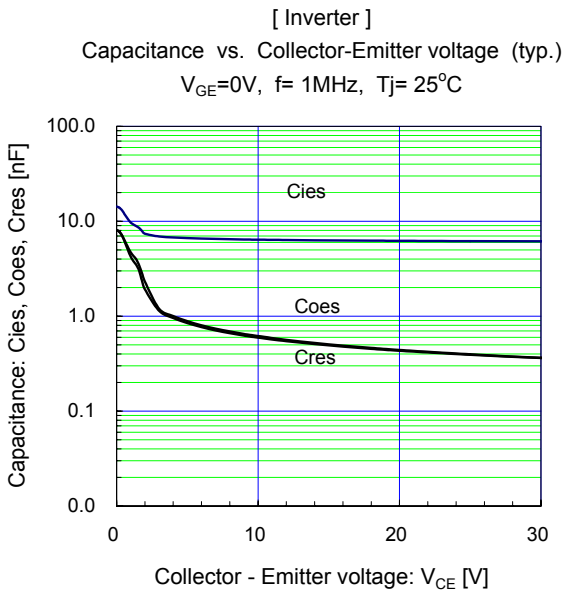
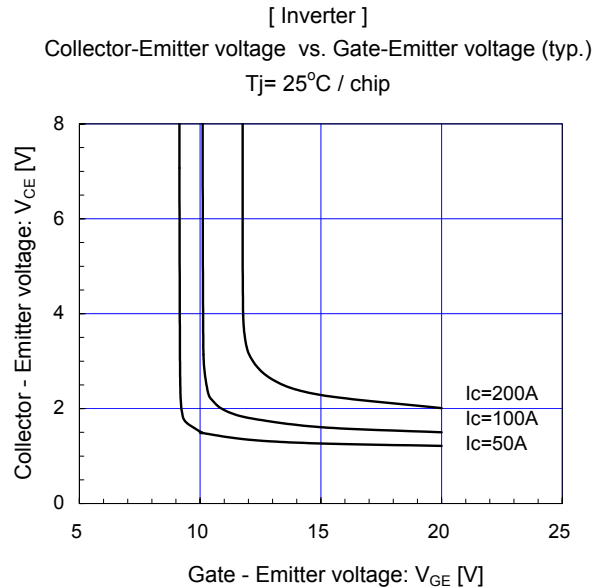
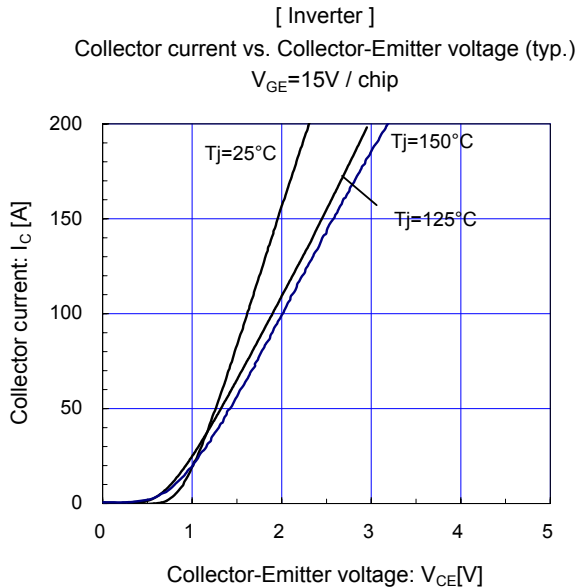
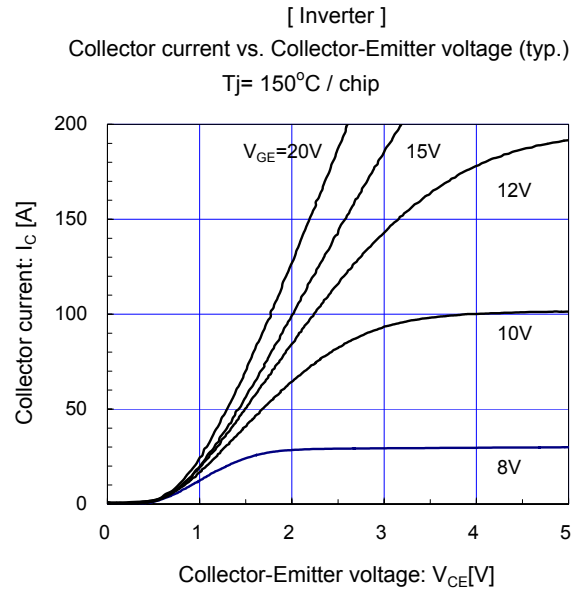
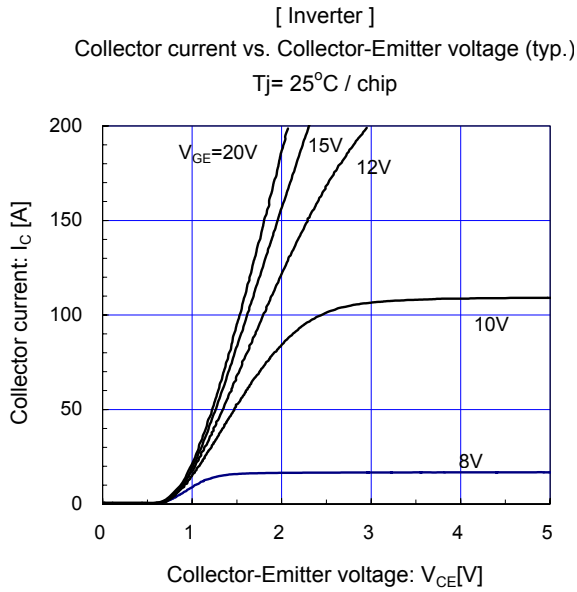
Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 600V	-	-	1.0	mA	
	Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = ±20V	-	-	200	nA	
	Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 100mA	6.2	6.7	7.2	V	
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> = 25°C	-	2.10	2.55	V
				T <sub>j</sub> = 125°C	-	2.40	-	
				T <sub>j</sub> = 150°C	-	2.50	-	
		V <sub>CE(sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>c</sub> = 100A	T <sub>j</sub> = 25°C	-	1.60	2.05	
				T <sub>j</sub> = 125°C	-	1.90	-	
	T <sub>j</sub> = 150°C	-	2.00	-				
	Internal gate resistance	R <sub>g(int)</sub>	-	-	9	-	Ω	
	Input capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0V, f = 1MHz	-	6.4	-	nF	
	Turn-on time	ton	V <sub>CC</sub> = 300V I <sub>c</sub> = 100A V <sub>GE</sub> = +15 / -15V R <sub>G</sub> = 13Ω	-	0.36	1.20	μs	
		tr		-	0.25	0.60		
		tr(i)		-	0.07	-		
	Turn-off time	toff	R <sub>G</sub> = 13Ω	-	0.52	1.20	μs	
tf		-		0.03	0.45			
Forward on voltage	V <sub>F</sub> (terminal)	I <sub>F</sub> = 100A	T <sub>j</sub> = 25°C	-	2.10	2.55	V	
			T <sub>j</sub> = 125°C	-	2.00	-		
			T <sub>j</sub> = 150°C	-	2.00	-		
	V <sub>F</sub> (chip)	I <sub>F</sub> = 100A	T <sub>j</sub> = 25°C	-	1.60	2.05		
			T <sub>j</sub> = 125°C	-	1.50	-		
T <sub>j</sub> = 150°C	-	1.47	-					
Reverse recovery time	trr	I <sub>F</sub> = 100A	-	-	0.35	μs		
Brake	Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> = 0V V <sub>CE</sub> = 600V	-	-	1.0	mA	
	Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> = 0V V <sub>GE</sub> = +20 / -20V	-	-	200	nA	
	Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 50A	T <sub>j</sub> = 25°C	-	1.85	2.30	V
				T <sub>j</sub> = 125°C	-	2.15	-	
				T <sub>j</sub> = 150°C	-	2.25	-	
		V <sub>CE(sat)</sub> (chip)	V <sub>GE</sub> = 15V I <sub>c</sub> = 50A	T <sub>j</sub> = 25°C	-	1.60	2.05	
				T <sub>j</sub> = 125°C	-	1.90	-	
	T <sub>j</sub> = 150°C	-	2.00	-				
	Internal gate resistance	R <sub>g(int)</sub>	-	-	0	-	Ω	
	Turn-on time	ton	V <sub>CE</sub> = 300V I <sub>c</sub> = 50A V <sub>GE</sub> = +15 / -15V R <sub>G</sub> = 43Ω	-	0.36	1.20	μs	
tr		-		0.25	0.60			
Turn-off time	toff	R <sub>G</sub> = 43Ω	-	0.52	1.20	μs		
	tf		-	0.03	0.45			
Reverse current	I <sub>RRM</sub>	V <sub>R</sub> = 600V	-	-	1.00	mA		
Converter	Forward on voltage	I <sub>F</sub> = 100A	terminal	-	1.75	2.20	V	
			chip	-	1.25	-		
Reverse current	I <sub>RRM</sub>	V <sub>R</sub> = 800V	-	-	1.0	mA		
Thermistor	Resistance	T = 25°C	-	5000	-	Ω		
		T = 100°C	465	495	520			
B value	B	T = 25 / 50°C	3305	3375	3450	K		

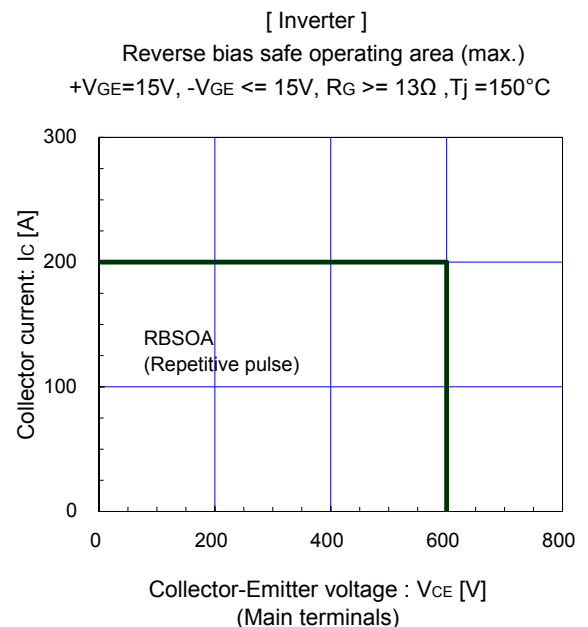
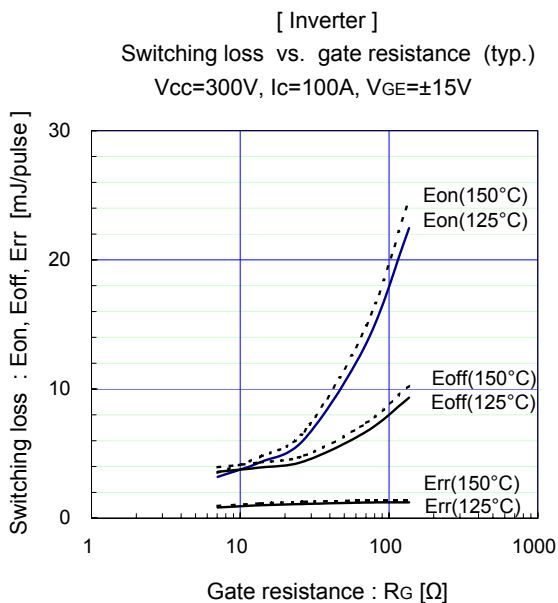
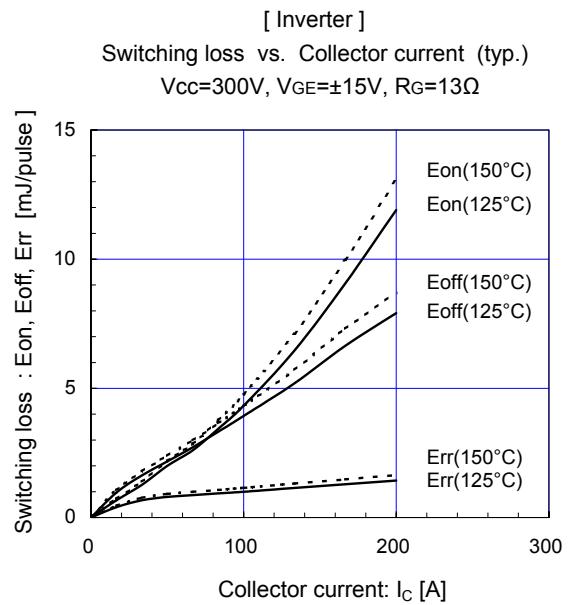
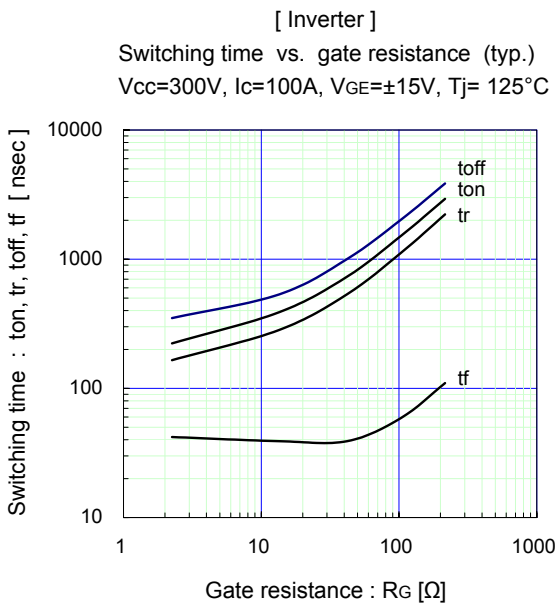
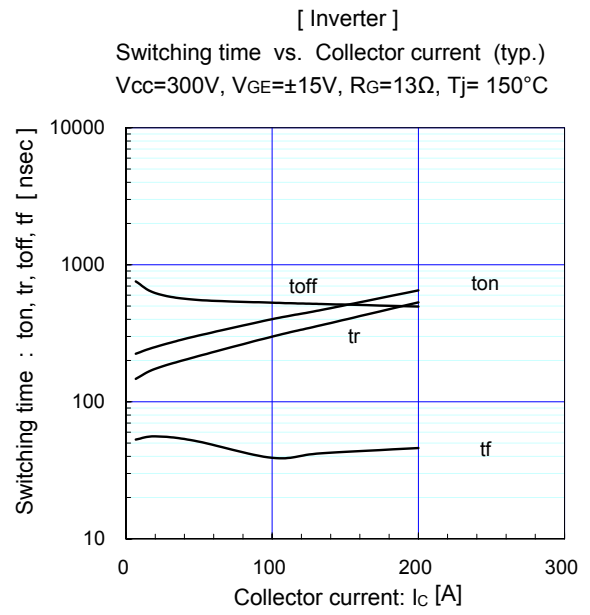
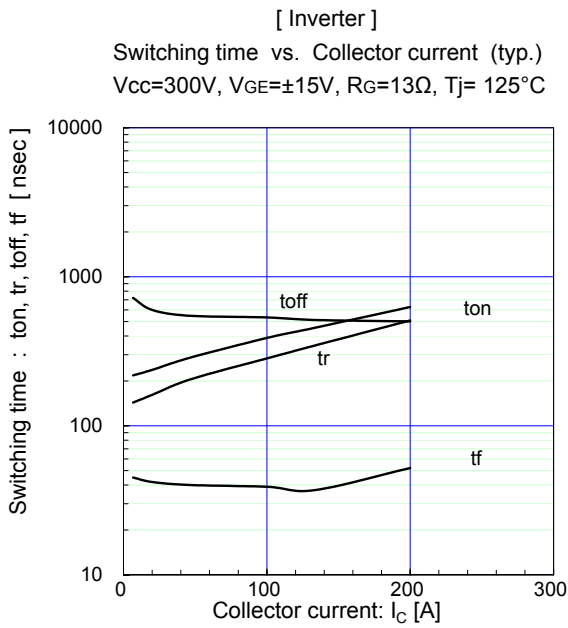
## ● Thermal resistance characteristics

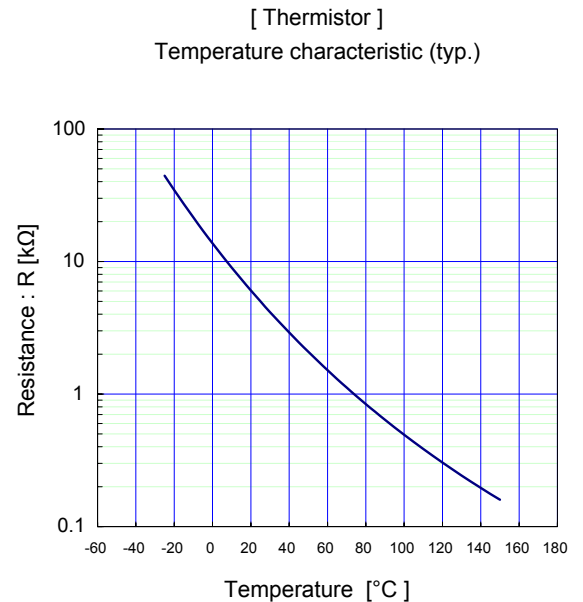
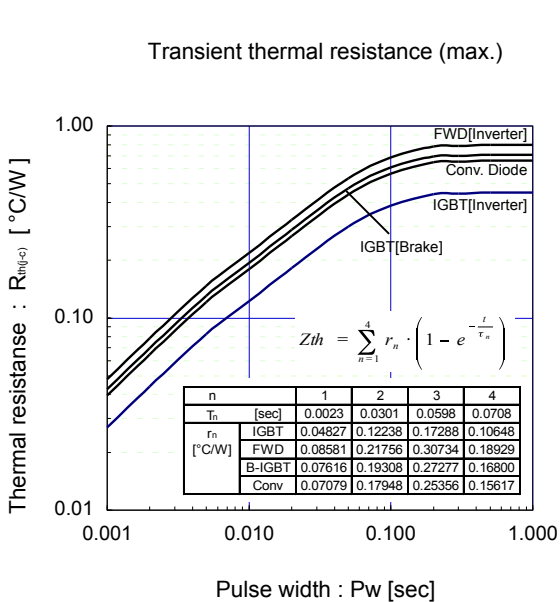
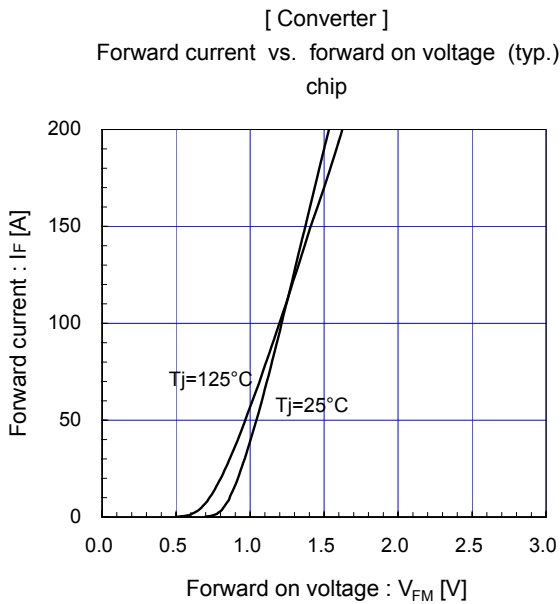
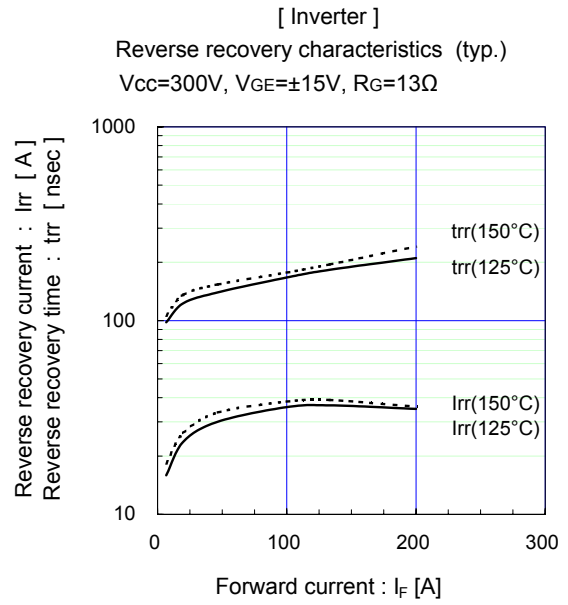
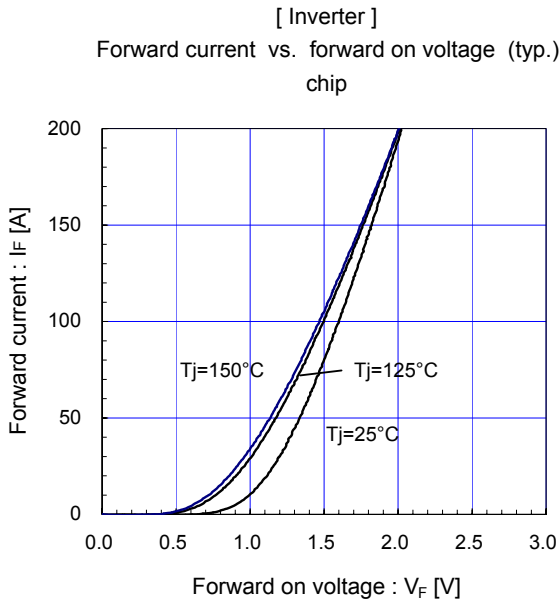
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R <sub>th(j-c)</sub>	Inverter IGBT	-	-	0.45	°C/W
		Inverter FWD	-	-	0.80	
		Brake IGBT	-	-	0.71	
		Converter Diode	-	-	0.66	
Contact thermal resistance (1device) (*4)	R <sub>th(c-f)</sub>	with Thermal Compound	-	0.05	-	

Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

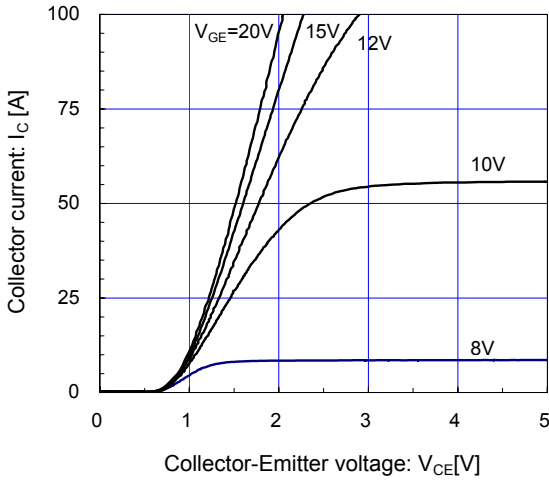
■ Characteristics (Representative)



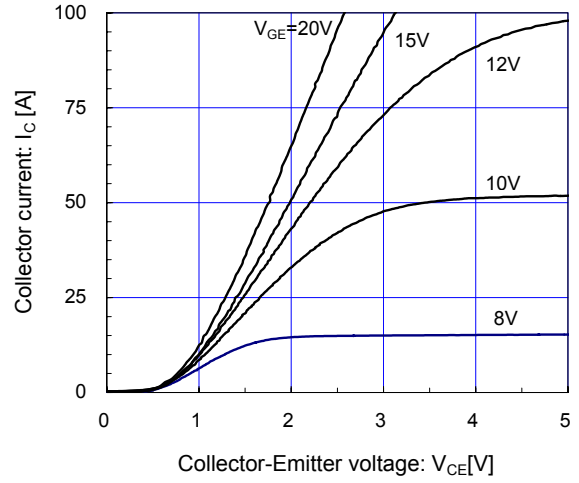




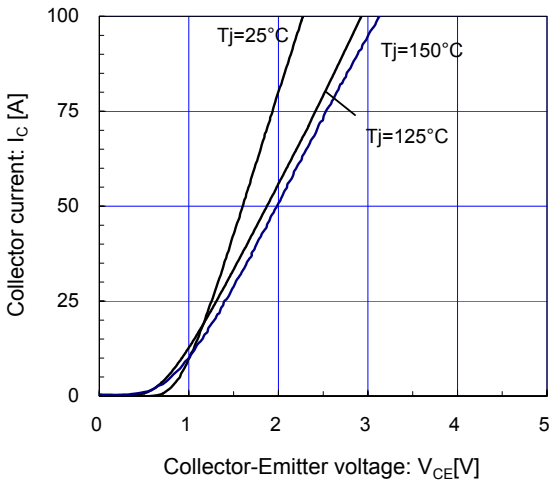
[ Brake ]  
Collector current vs. Collector-Emittor voltage (typ.)  
Tj= 25°C / chip



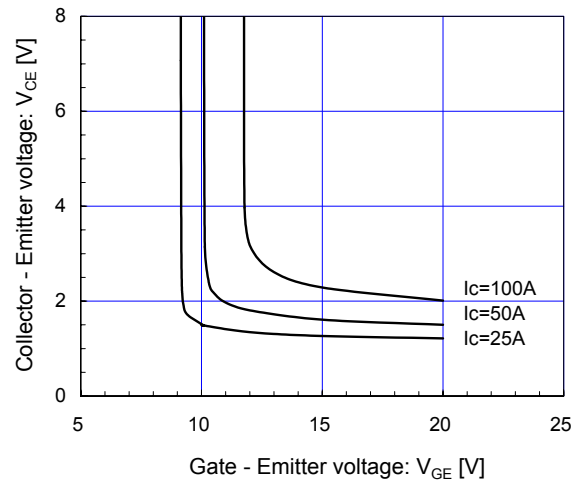
[ Brake ]  
Collector current vs. Collector-Emittor voltage (typ.)  
Tj= 150°C / chip



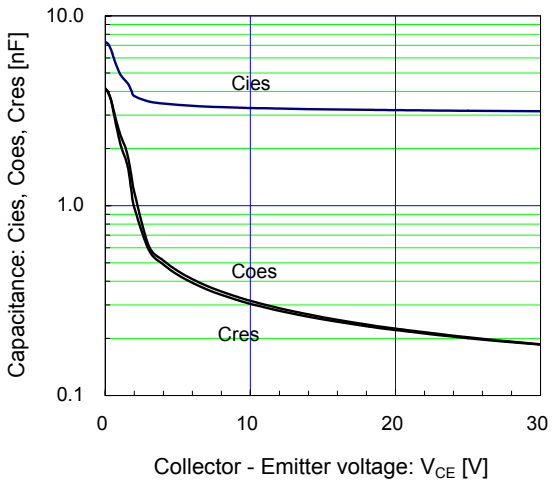
[ Brake ]  
Collector current vs. Collector-Emittor voltage (typ.)  
VGE=15V / chip



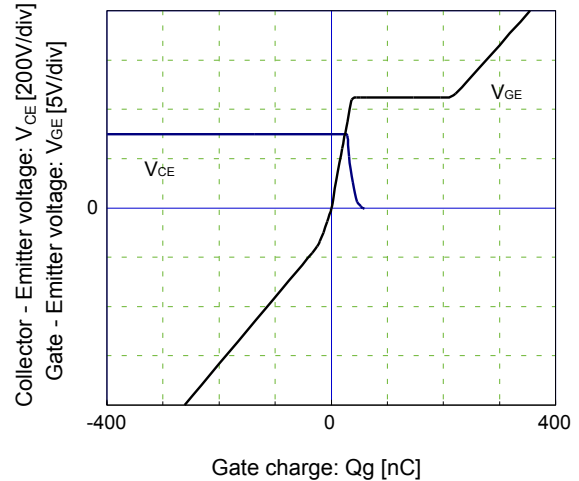
[ Brake ]  
Collector-Emittor voltage vs. Gate-Emittor voltage (typ.)  
Tj= 25°C / chip



[ Brake ]  
Capacitance vs. Collector-Emittor voltage (typ.)  
VGE=0V, f= 1MHz, Tj= 25°C

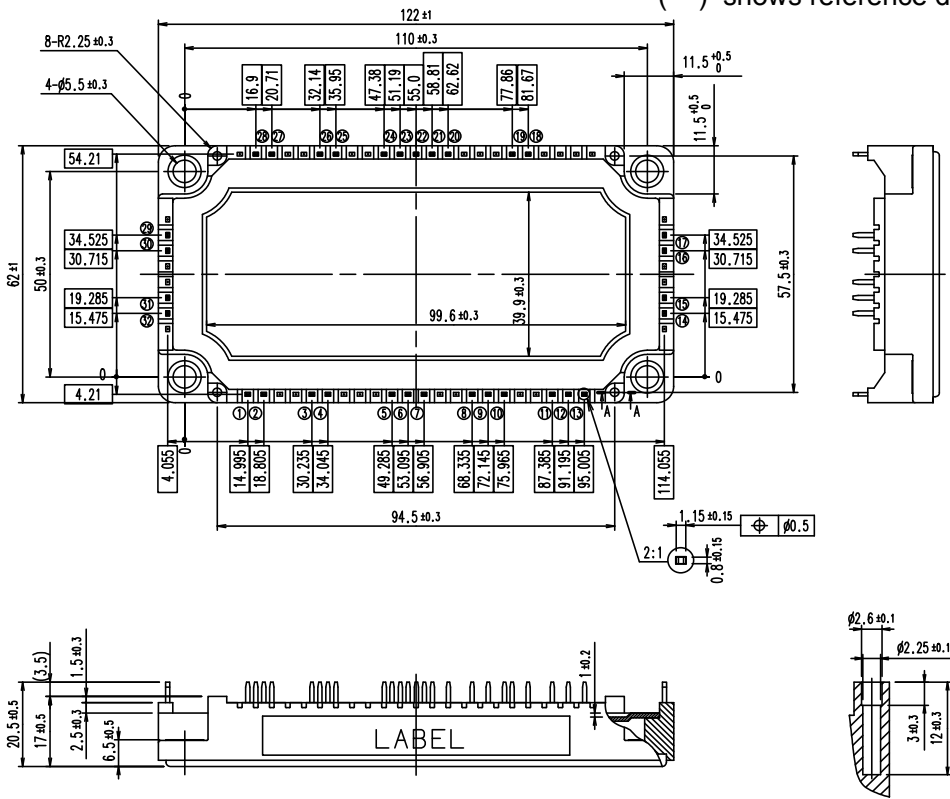


[ Brake ]  
Dynamic gate charge (typ.)  
Vcc=300V, Ic=50A, Tj= 25°C



■ Outline Drawings(Unit:mm)

□ shows theoretical dimension.  
 ( ) shows reference dimension.

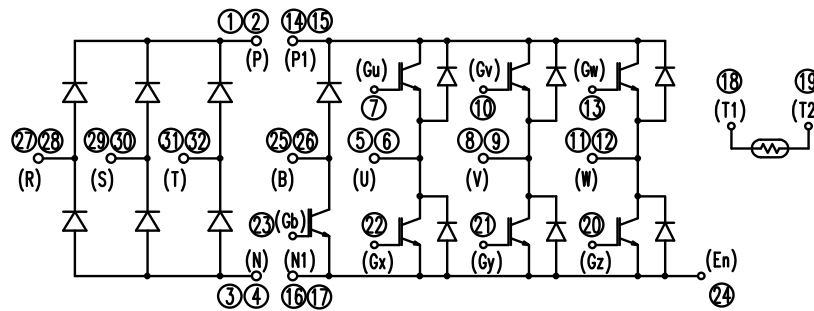


Section A-A

Weight: 310g(typ.)

■ Equivalent Circuit

[ Converter ]      [ Brake ]      [ Inverter ]      [ Thermistor ]



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**IGBT Modules**

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